





APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	· CONFIRMATION NO.
09/651,998	08/31/2000	Lingyi A Zheng	M4065.0315/P315	2931
24998	7590 07/29/2003			
DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP			EXAMINER	
	2101 L STREET NW WASHINGTON, DC 20037-1526		TSAI, H JEY	
			ART UNIT	PAPER NUMBER
		•	2812	
	•		DATE MAILED: 07/29/2003	•

Please find below and/or attached an Office communication concerning this application or proceeding.

8	Amml:4: N	(Applicant/a)
	Application No.	Applicant(s)
Office Author Occasion	09/651,998	ZHENG ET AL.
Office Action Summary	Examiner	Art Unit
	H.Jey Tsai	2812
The MAILING DATE of this communication Period for Reply	n appears on the cov rs	neet with the correspondence address
A SHORTENED STATUTORY PERIOD FOR R THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CI after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, - If NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b). Status	ON. FR 1.136(a). In no event, however on. a reply within the statutory minimieriod will apply and will expire SIX statute, cause the application to be mailing date of this communication.	may a reply be timely filed im of thirty (30) days will be considered timely. (6) MONTHS from the mailing date of this communication.
1) Responsive to communication(s) filed on		
2a) ☐ This action is FINAL . 2b) ☐		
3) Since this application is in condition for a closed in accordance with the practice up Disposition of Claims		nal matters, prosecution as to the ments is 935 C.D. 11, 453 O.G. 213.
4)⊠ Claim(s) <u>1-59</u> is/are pending in the applic	ation.	
4a) Of the above claim(s) is/are with	hdrawn from considerati	on.
5) Claim(s) is/are allowed.		
6)⊠ Claim(s) <u>1-59</u> is/are rejected.		
7) Claim(s) is/are objected to.		
8) Claim(s) are subject to restriction a	ind/or election requireme	ent.
Application Papers		
9) The specification is objected to by the Exam		
10) The drawing(s) filed on is/are: a)		
Applicant may not request that any objection		
11) The proposed drawing correction filed on _		
If approved, corrected drawings are required		n. ,
12)☐ The oath or declaration is objected to by th	e Examiner.	
Priority under 35 U.S.C. §§ 119 and 120		
13) Acknowledgment is made of a claim for fo	reign priority under 35 L	J.S.C. § 119(a)-(d) or (f).
a) ☐ All b) ☐ Some * c) ☐ None of:		
1. Certified copies of the priority docur	nents have been receiv	ed.
2. Certified copies of the priority docur	ments have been receiv	ed in Application No
3. Copies of the certified copies of the application from the Internation* See the attached detailed Office action for	al Bureau (PCT Rule 17	
14) Acknowledgment is made of a claim for dor	mestic priority under 35	J.S.C. § 119(e) (to a provisional application).
a) ☐ The translation of the foreign languag 15)☐ Acknowledgment is made of a claim for do		
Attachment(s)		
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-94) Information Disclosure Statement(s) (PTO-1449) Paper No. 	8) 5) 🔲 N	terview Summary (PTO-413) Paper No(s) otice of Informal Patent Application (PTO-152) ther:
.S. Patent and Trademark Office PTO-326 (Rev. 04-01) Offi	ce Action Summary	Part of Paper No. 25

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Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-59 stand rejected under 35 U.S.C. 103(a) as being unpatentable over Shue et al. 6,380,056 in view of Ma 6,207,589, both are previously applied.

The reference(s) teach the features:

Shue et al. substantially discloses a method of forming a capacitor on the semiconductor device, which includes:

forming a conductive layer 12,

forming a silicon nitride layer 18, col. 7, lines 8+,

contacting silicon nitride layer with a mixture of hydrogen and oxidizing oxygen and nitrous gases (N₂O) to oxidize the silicon nitride layer, see col. 7, lines 33+ and claims 11-14, forming an upper capacitor electrode 22.

The difference between the reference(s) and the claims are as follows:

Shue et al. lacks thickness of the dielectric layer. However, Ma teaches dielectric layer 56 is between 2-200 A° and contacting dielectric layer 56 with a mixture of hydrogen and oxidizing oxygen and nitrous gases (N₂O) to condition the high k dielectric layer and to include oxygen in the alloy film of metal oxide in col. 6, lines 1+. And, the specific coating thickness, gas flow rate and temperature as claimed are taken to be obvious since these are variables of art recognized importance which are subject to routine experimentation and optimization and discovery of an optimum value for a known process is obvious. In re Aller, 105 USPQ 233 (CCPA 1955). And, even if applicants' modification results in great improvement and utility

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over the prior art, it may still not be patentable if the modification was within the capabilities of one skilled in the art, In Re Sola 25 USPQ 433.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to have modified Shue et al.'s process with a capacitor dielectric layer of between 2-200 A° and oxidizing dielectric layer with a mixture of hydrogen and oxidizing oxygen and nitrous gases (N₂O).

Applicant's arguments filed on May 12, 2003 have been fully considered but they are not persuasive.

Applicants contend that neither Shur nor Ma discloses forming an oxidation layer over a dielectric layer over a dielectric layer or silicon nitride layer as recited in independent claims 1 and 40. This is not found to be persuasive because Shur clearly teaches forming an oxidation layer over a dielectric layer over a dielectric layer or silicon nitride layer by contacting silicon nitride layer with a mixture of hydrogen and oxidizing oxygen and nitrous gases (N₂O) to oxidize the silicon nitride layer, see col. 7, lines 33+ and claims 11-14.

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

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however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry of a general nature or clerical matters or relating to the status of this application or proceeding should be directed to the Group customer service whose telephone number is (703) 306-3329 and Fax number (703) 306-5515. Group receptionist telephone number 703-308-0956.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to H. Jey Tsai whose telephone number is (703) 308-1374. The examiner can normally be reached on from 7:00 Am to 4:00 Pm., Monday thru Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling can be reached on (703) 308-3325. The fax phone number for this Group is (703) 305-3431.

hjt 7/24/03

H. Jey Tsai

Primary Examiner
Patent Examining Group 2800